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August 2024

FSUSB30 Low-Power, Two-Port, High-Speed USB 2.0 (480Mbps) Switch

Features

- 2 Low On Capacitance: 3.7pF (Typical)
- ? Low On Resistance: 6.5Ω (Typical)
- ? Low Power Consumption: 1µA (Maximum)
- 10μ A Maximum I_{CCT} over an Expanded Control Voltage Range (V_{IN} = 2.6V, V_{CC} = 4.3V)
- ? Wide -3dB Bandwidth, >720MHz
- ? 8kV ESD Protection
- ? Power-Off Protection when $V_{CC} = 0V$; D+/D- Pins can Tolerate up to 5.5V
- ? Packaged in:
 - 10-lead MicroPak[™] (1.6 x 2.1mm)
 - 10-lead MSOP
 - 10-lead UMLP (1.4 x 1.8mm)

Applications

? Cell phone, PDA, Digital Camera, and Notebook LCD Monitor, TV, and Set-top Box

Related Application Notes

Ordering Information

AN-6022 Using the FS JSB30 / FSUSB31 to Comply with USB 2.0 Fault Condition Requirements

Description

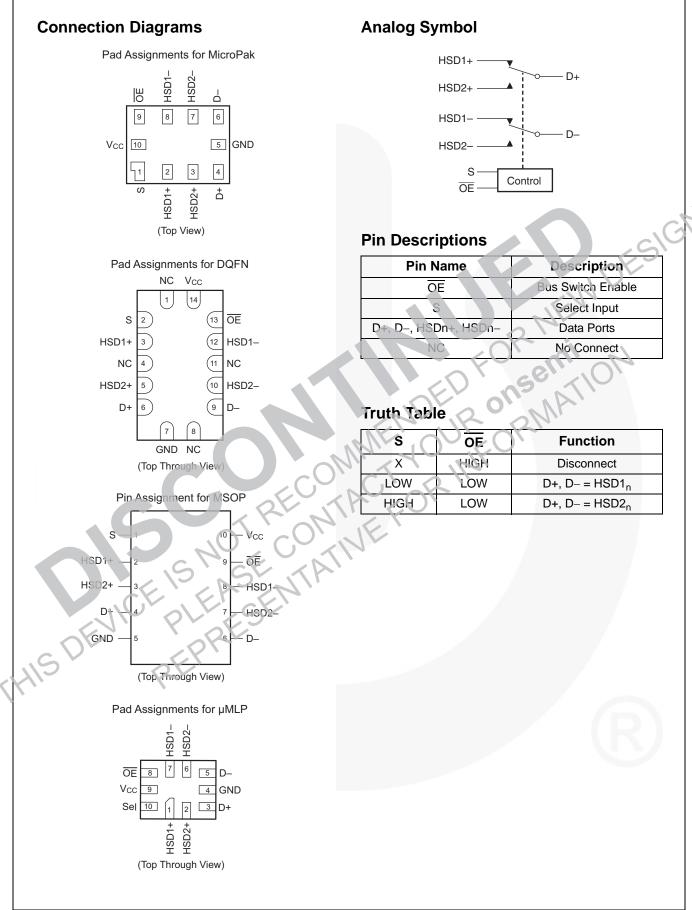
The FSUSB30 is a low-power, two-port high-speed USB 2.0 switch. Configured as a double-pole double-throw (DPDT) switch, it is optimized for switching between two high-speed (480Mbps) sources or a Hi-speed and Full-Speed (12Mbps) source. The FSUSB30 is compatible with the requirements of USB2.0 and features an extremely low on capacitance (C_{ON}) of 3.7pF. The wide bandwidth of this device (720Mi-Iz) exceeds the bandwidth needed to pass the third harmonic, resulting in signals with minimum edge and phase distortion. Superior channel-to-channel crosstalk minimizes interference.

The FSUSB30 contains special circuity on the D+/Doins which allows the device to withstand an overvoltage condition when powered off. This device is also designed to minimize current consumption even when the control voltage applied to the S pin, is lower than the supply voltage (V_{CC}). This feature is especially valuable to ultraportable applications such as cell phones, allowing for direct interface with the general purpose I/Os of the baseband processor. Other applications include switching and connector sharing in portable cell phones, PDAs, digital cameras, printers, and notebook computers.

			SV .1	
	Order Number	Package Number	Product Code Top Mark	Package Description
	FSUSB30L10X	MAC010A	۴J	10-Lead MicroPak, 1.6 x 2.1mm
	FSUSB30MUX	MUA10A	FSUSB30	10-Lead Molded Small Outline Package (MSOP), JEDEC MO- 187, 3.0mm Wide
	FSUSB30UMX	MLP010A	GJ	10-Lead, Quad, Ultrathin, MLP (UMLP) 1.4 x 1.8mm

FSUSB30 Vcc 1D+ USB2.0 Controller 1D-Set Top Box USB Connector (STB) CPU Dor DSP 2D+ DVR or Processor Mass Storage 2D-Control Controller OF Figure 1. Typical Application

MicroPak™ is a trademark of Fairchild Semiconductor Corporation.



Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Param	Minimum	Maximum	Unit	
V _{CC}	Supply Voltage		-0.5	+5.5	V
V _{CNTRL}	DC Input Voltage ⁽¹⁾		-0.5	V _{CC}	V
		HSDnX	0.5	V _{CC}	V
V _{SW}	DC Switch Voltage ⁽¹⁾	D+,D- when $V_{CC} > 0$	0.5	V _{CC}	V
		D+,D- when $V_{CC} = 0$	-0.50	V _{CC}	V
I _{IK}	DC Input Diode Current		-50		mA
I _{OUT}	DC Output Current		50	mA	
T _{STG}	Storage Temperature		-65	+150	°C
ESD	Human Body Model	All Pins		8	kV
LOD	Thuman Body Model	I/O to GND		8	kV

Note:

1. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.⁽²⁾

Symbol	Parameter	Minimum	Maximum	Unit
V _{CC}	Supply Voltage	3.0	4.3	V
V _{IN}	Control Input Voltage	0	V _{CC}	V
V _{SW}	Switch Input Voltage	0	V _{CC}	V
TA	Operating Temperature	-40	+85	°C
ΘJ _A	Thermal Resistance, 10 MicroPak		250	°C/W

Note:

2. Control input must be held HIGH or LOW and it must not float.

DC Electrical Characteristics

All typical values are at 25°C unless otherwise specified.

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = -	40°C to	+85°C	Unit
Symbol	Farameter	Conditions	VCC (V)	Min.	Тур.	Max.	Unit
V _{IK}	Clamp Diode Voltage	I _{IN} = -18mA	3.0			-1.2	V
V			3.0 to 3.6	1.3			V
V _{IH}	Input Voltage HIGH		4.3	1.7			V
V			3.0 to 3.6			0.5	V
V _{IL}	Input Voltage LOW		4.3			0.7	V
I _{IN}	Control Input Leakage	$V_{SW} = 0.0V$ to V_{CC}	4.3	-1.0		1.0	μA
I _{OZ}	OFF State Leakage	$0 \le Dn, HSD1_n, HSD2_n \le V_{CC}$	4.3	-2.0		2.0	μA
I _{OFF}	Power OFF Leakage Current (D+, D–)	$V_{SW} = 0V$ to 4.3V, $V_{CC} = 0V$	0	-2.0		2.0	μA
Р	Quitab On Desistance ⁽³⁾	V _{SW} = 0.4V, I _{ON} = -8mA	3.0		6.5	10.0	Ω
R _{ON}	Switch On Resistance ⁽³⁾	V _{SW} = 0V, I _O = 30mA at 25°C	3.6		1 C	7.0	Ω
ΔR_{ON}	Delta R _{ON} ⁽⁴⁾	V _{SW} = 0.4V, I _{ON} = -8mA	3.0	0	0.35		Ω
R _{ON} Flatness	R _{ON} Flatness ⁽³⁾	V _{SW} = 0.0V - 1.0V I _{ON} = -8mA	3.0	D	2.0	3	Ω
I _{CC}	Quiescent Supply Current	$V_{CNTRL} = 0.0 V \text{ or } V_{CC},$ $I_{OUT} = 0$	4.3	ns	121	1.0	μA
I _{CCT}	Increase in I _{CC} Current per Control Voltage	V _{CNTRL} (control input) = 2.6V	4 3	R	20	10.0	μA

Notes:

3. Measured by the voltage drop between Dn, HSD1_n, HSD2_n pins at the indicated current through the switch. On resistance is determined by the lower of the voltage on the two ports.

4. Guaranteed by characterization.

AC Electrical Characteristics

All typical values are for V_{CC} = 3.3V at 25°C unless otherwise specified.

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = -4	40°C to	+85°C	Unit	Figure
Oynibol	T and meter	Solutions		Min.	Тур.	Max.	Onit	Number
t _{ON}	Turn-On Time S, OE to Output	$HD1_n$, $HD2_n = 0.8V$, $R_L = 50\Omega$, $C_L = 5pF$	3.0 to 3.6		13	30	ns	Figure 9
toff	Turn-Off Time S OE to Output	$\label{eq:HD1_n} \begin{split} \text{HD1}_{\text{n}}, \ \text{HD2}_{\text{n}} &= 0.8 \text{V}, \\ \text{R}_{\text{L}} &= 50 \Omega, \ \text{C}_{\text{L}} &= 5 \text{pF} \end{split}$	3.0 to 3.6		12	25	ns	Figure 9
t _{PD}	Propagation Delay ⁽⁴⁾	$R_L = 50\Omega, C_L = 5pF$	3.3		0.25		ns	Figure 7 Figure 8
t _{BBM}	Break-Before-Make		3.0 to 3.6	2.0		6.5	ns	Figure 10
O _{IRR}	Off Isolation (Non-Adjacent)	$f = 240MHz, R_T = 50\Omega$	3.0 to 3.6		-30		dB	Figure 13
Xtalk	Non-Adjacent Channel Crosstalk	R _T = 50Ω, f = 240MHz	3.0 to 3.6		-45		dB	Figure 14
BW	–3dB Bandwidth	$R_T = 50\Omega, C_L = 0pF$	3.0 to 3.6		720		MHz	Figure 12
500		$R_T = 50\Omega, C_L = 5pF$	5.0 10 5.0		550			i igule 12

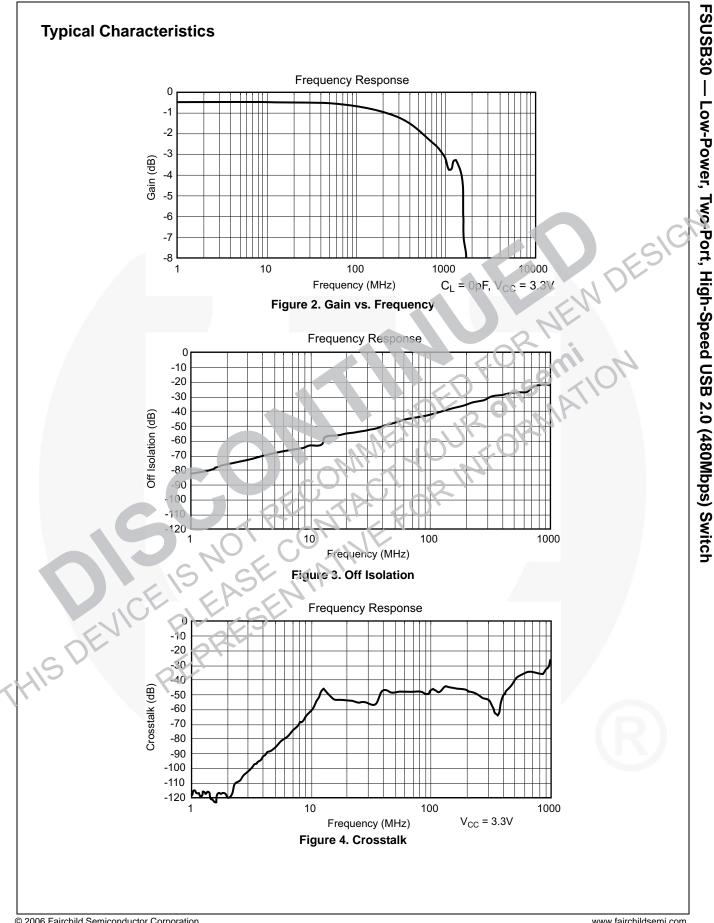
	FSUSB30 -
	— Low-Power, Two
	Two-Port, High-
	High-Speed
	-Speed USB 2.0 (480)
-	(480Mbps)
	Switch

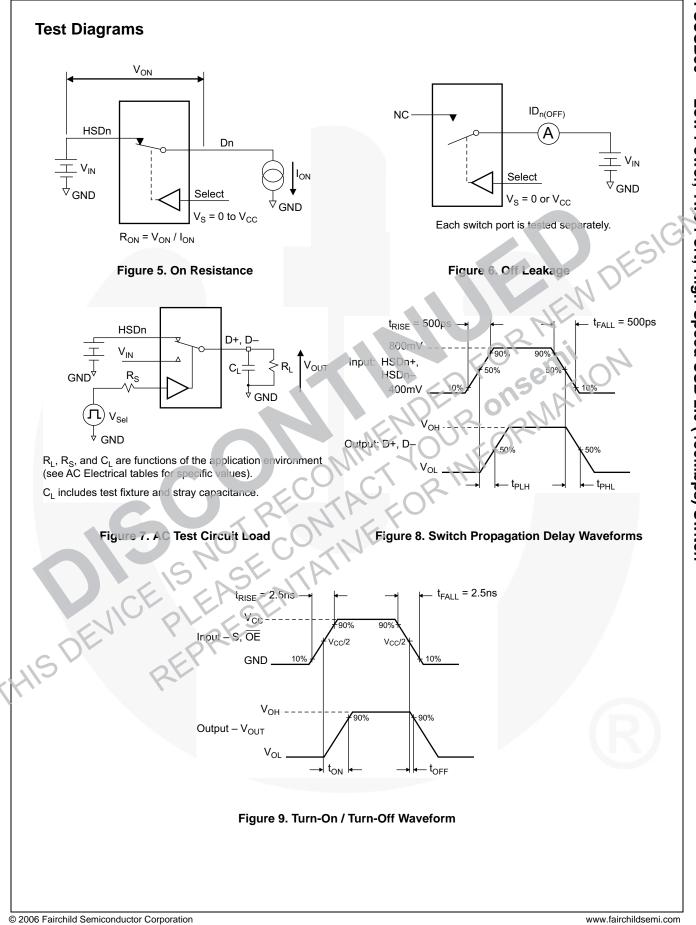
Symbol	Parameter	Conditions	V _{CC} (V)	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			Units	Figure
Symbol		conditions	• 66 (•)	Min.	Тур.	Max.	Units	Number
t _{SK(O)}	Channel-to-Channel Skew ⁽⁵⁾	$R_L = 50\Omega, C_L = 5pF$	3.0 to 3.6		50		ps	Figure 7 Figure 11
t _{SK(P)}	Skew of Opposite Transitions of the Same Output ⁽⁵⁾	$R_L = 50\Omega, C_L = 5pF$	3.0 to 3.6		20		ps	Figure 7 Figure 11
tj	Total Jitter ⁽⁵⁾	$R_L = 50\Omega, C_L = 5pF,$ $t_R = t_F = 500ps at 480 Mbps$ (PRBS = 2 ¹⁵ – 1)	3.0 to 3.6		200		ps	

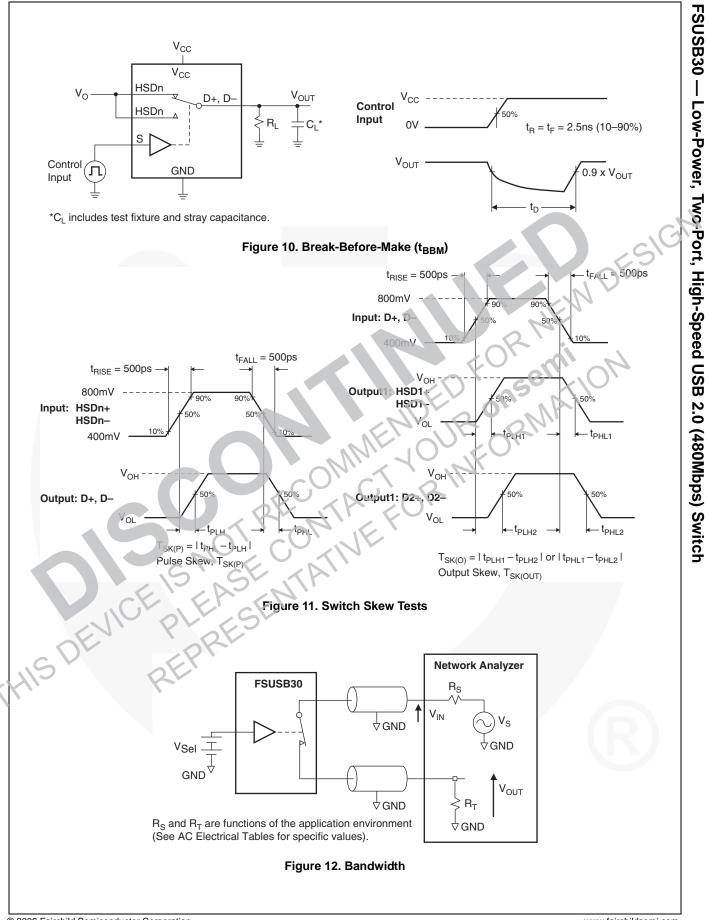
Note:

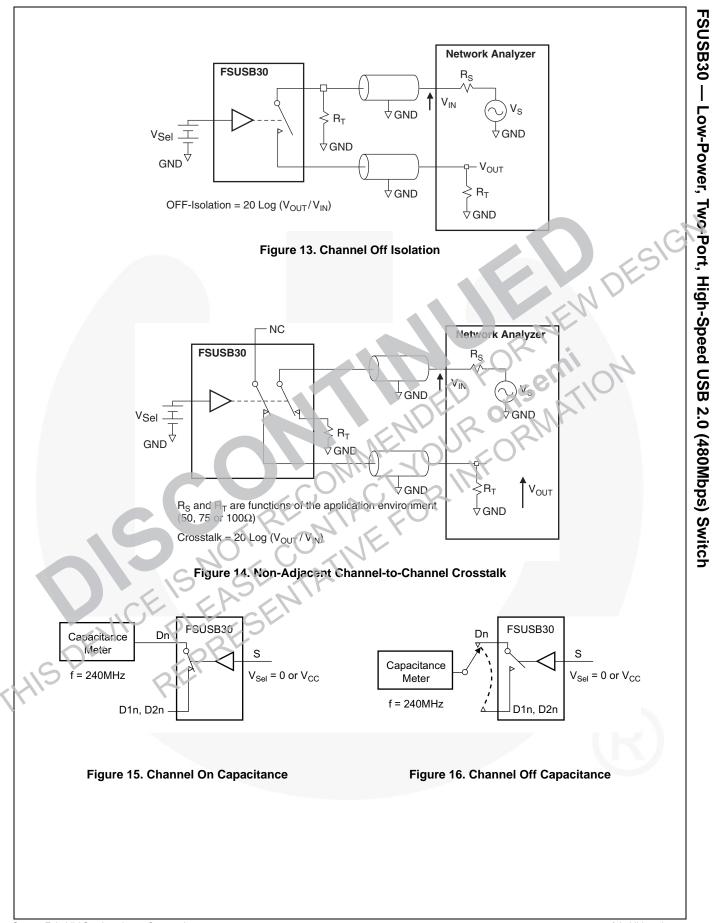
Capacitance

Parameter pontrol Pin Input Capacitance I _n , D2 _n , Dn On Capacitance I _n , D2 _n Off Capacitance	Conditions $V_{CC} = 0V$ $V_{CC} = 3.3$, $\overline{OE} = 0V$ V_{CC} and $\overline{OE} = 3.3$. Min.	10°C +85°C 1yp. Max. 1.5 3.7 2.5	PF PF PF	Figure Numbe Figure 1 Figure 1 Figure 1
I_n , D2 _n , Dn On Capacitance I_n , D2 _n Off Capacitance	$V_{CC} = 3.3, \overline{OE} = 0V$ V_{CC} and $\overline{OE} = 3.3$	NDE	3.7 2.5	pF	Figure 1
I _n , D2 _n Off Capacitance	V_{CC} and $\overline{OE} = 3.3$	104	2.5		-
		104		pF	Figure 1
c 0	NIME	NOL	RORI	1.	
CE IS ASE	NTAT				
	CE IS NOT	CE IS NOT CONVE	CE IS NOT CONVER	CE IS NOT CONVERTINE OR INFORM	CEISING CONVERT









Application Guidance: Meeting USB 2.0 Vbus Short Requirements

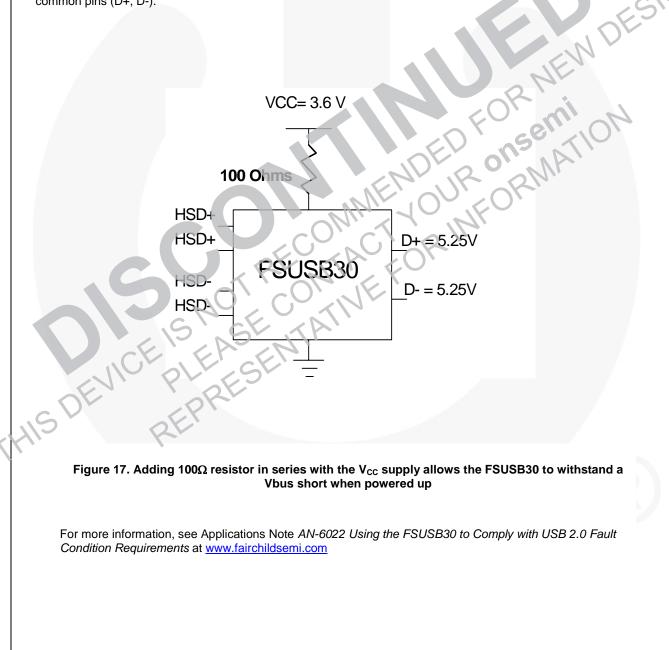
In section 7.1.1 of the USB 2.0 specification, it notes that USB devices must be able to withstand a Vbus short to D+ or D- when the USB devices is either powered off or powered on. The FSUSB30 can be successfully configured to meet both these requirements.

Power-Off Protection

For a Vbus short circuit, the switch is expected to withstand such a condition for at least 24 hours. The FSUSB30 has specially designed circuitry which prevents unintended signal bleed through as well as guaranteed system reliability during a power-down, overvoltage condition. The protection has been added to the common pins (D+, D-).

Power-On Protection

The USB 2.0 specification also notes that the USB device should be capable of withstanding a Vbus short during transmission of data. Fairchild recommends adding a 100 Ω series resister between the switch VCC pin and supply rail to protect against this case. This modification works by limiting current flow back into the V_{CC} rail during the over-voltage event so current remains within the safe operating range. In this application, the switch passes the full 5.25V input signal through to the selected output, while maintaining specified off isolation on the un-selected pins.



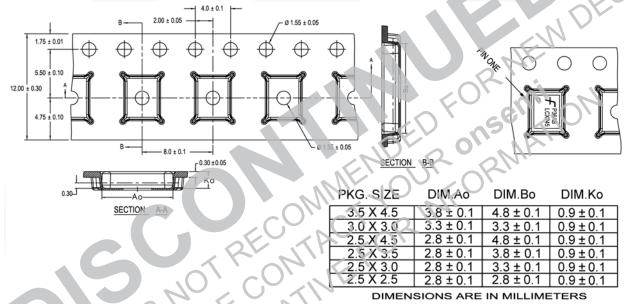
Tape and Reel Specifications

Tape Format for DQFN

Package Designator	Tape Section	Number Cavities	Cavity Status	Cover Tape Status
	Leader (Start End)	125 (typ)	Empty	Sealed
BQX	Carrier	2500/3000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

Tape Dimensions

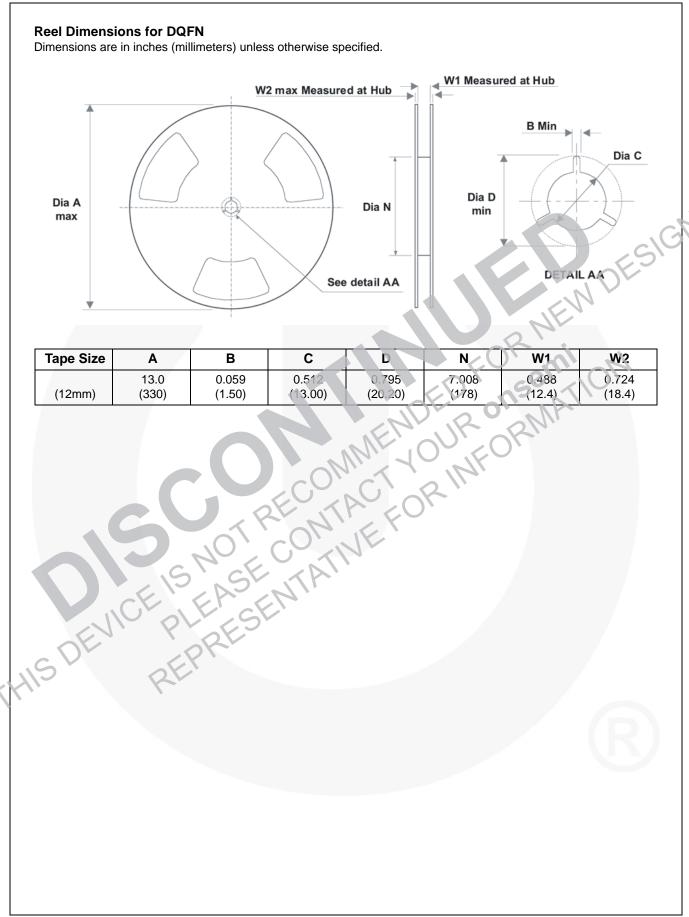
Dimenions are in millimeters unless otherwise specified.

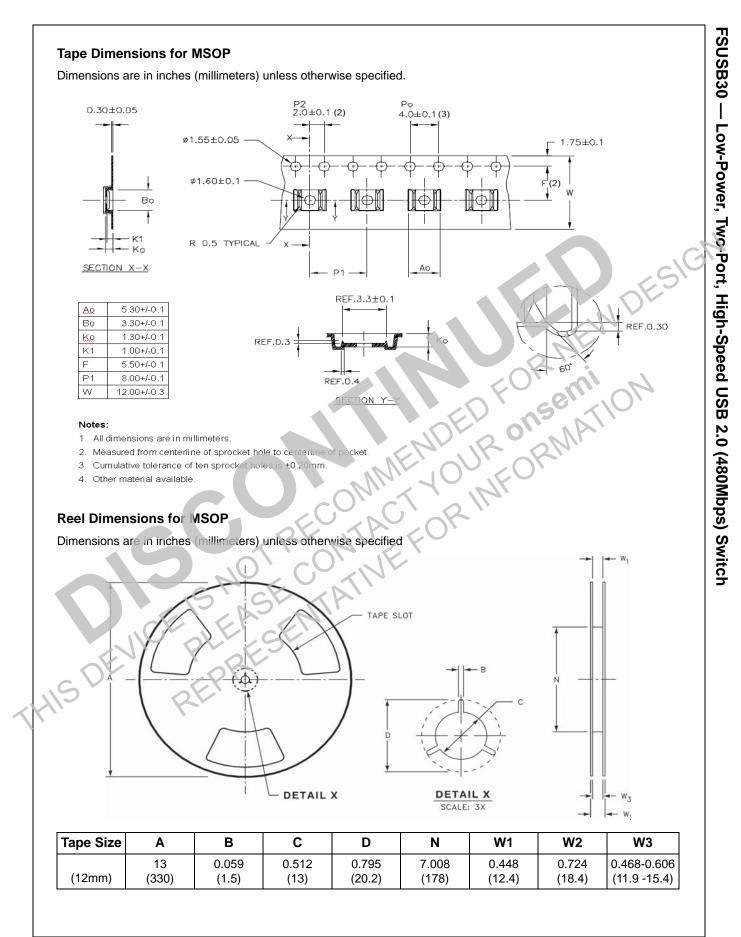


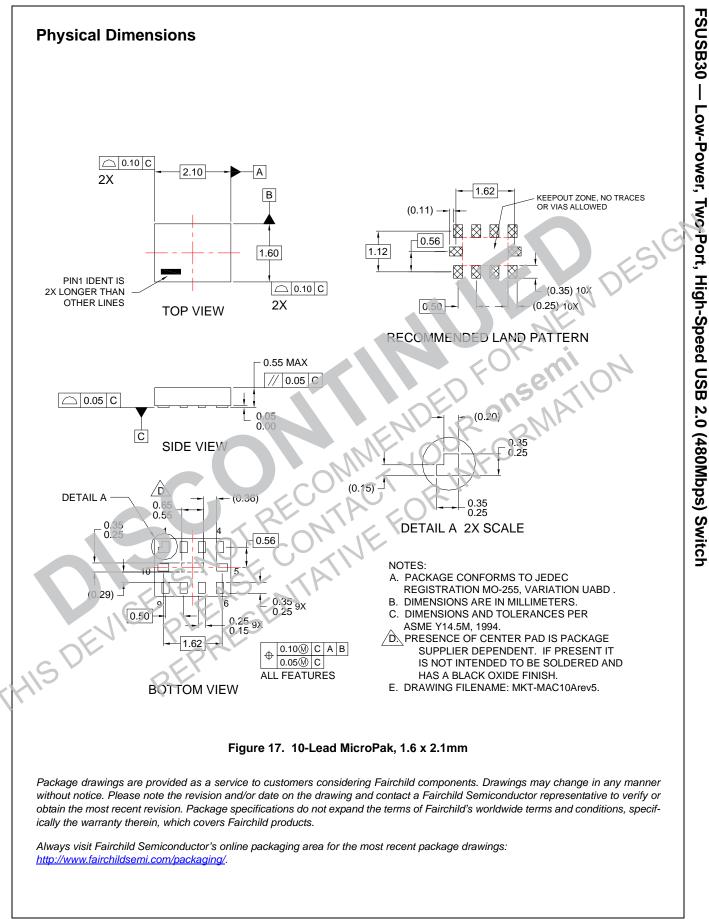
NOTES: unless otherwise specified

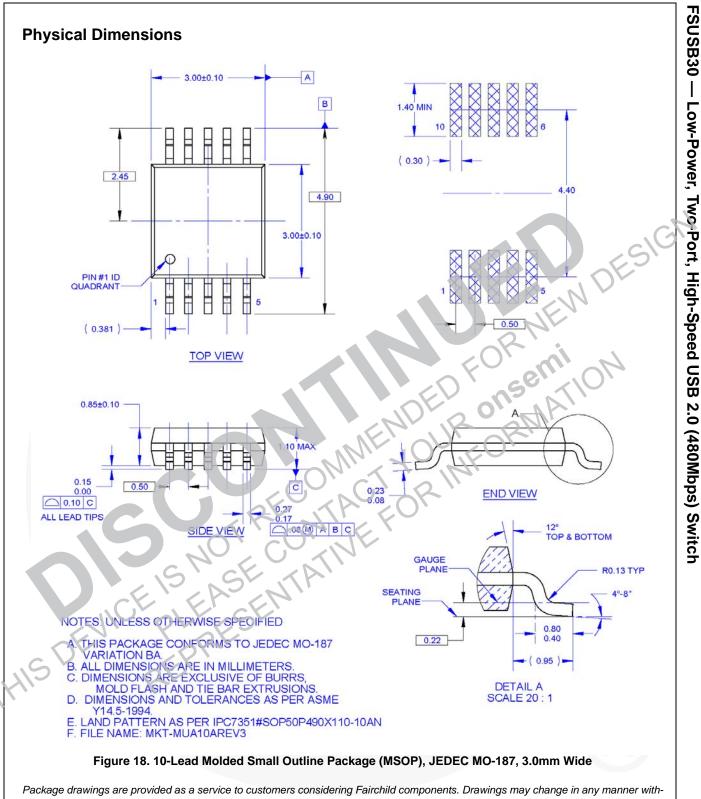
1. Cummulative pitch for feeding holes and cavities (chip pockets) not to exceed 0.008[0.20] over 10 pitch span.

- 2. Smallest allowable bending radius.
- 3. Thru hole in side cavity is centered within cavity.
- 4. Tolerance is ±0.002[0.05] for these dimensions on all 12mm tapes.
- 5. Ao and Bo measured on a plane 0 120[0.30] above the bottom of the pocket.
- 6 Ko measured from a place on the inside bottom of the pocket to the top surface of the carrier.
- 7. Pocket position relative to sprocket hole measured as true position of pocket. Not pocket hole.
- 8. Controlling dimension is millimeter. Diemension in inches rounded.



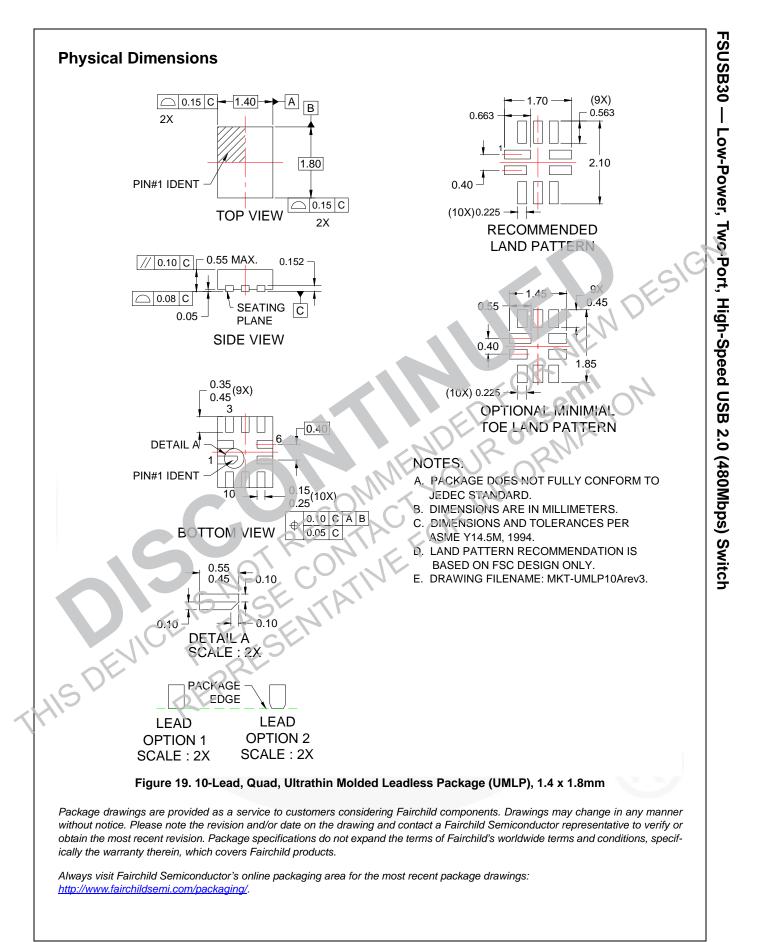






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